

HIGHER TECHNICAL INSTITUTE

ELECTRICAL ENGINEERING COURSE

DIPLOMA PROJECT

MOSFET SWITCHES IN POWER ELECTRONICS

E.1240

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SUMMARY:

Mosfet switches in power electronics

The whole work that follows is for the Diploma Project.

This project is under the supervision of Dr. Marouchos and deals with the design, construction and testing of choppers.

During the experiments the constructions were connected in DC chopper configuration.

For the completion of this project, main components that are used as switching devices while constructing and testing DC chopper are the MOSFET (Metal Oxide Semiconductor Field Effect Transistor) and the IGBT (Insulated Gate Bipolar Transistor.)

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